

8K-bit TTL bipolar PROM (1024 × 8)

82S181 / 82S181A

ORDERING INFORMATION

DESCRIPTION	ORDER CODE
24-Pin Plastic Dual-In-Line 600mil-wide	N82S181 N, N82S181A N
28-Pin Plastic Leaded Chip Carrier 450mil-square	N82S181 A, N82S181A A

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V_{CC}	Supply voltage	+7.0	V_{DC}
V_{IN}	Input voltage	+5.5	V_{DC}
V_O	Output voltage Off-State	+5.5	V_{DC}
T_{amb}	Operating temperature range	0 to +75	°C
T_{stg}	Storage temperature range	-65 to +150	°C

DC ELECTRICAL CHARACTERISTICS

 $0^{\circ}\text{C} \leq T_{amb} \leq +75^{\circ}\text{C}$, $4.75\text{V} \leq V_{CC} \leq 5.25\text{V}$

SYMBOL	PARAMETER	TEST CONDITIONS ^{1,2}	LIMITS			UNIT
			Min	Typ ³	Max	
Input voltage²						
V_{IL}	Low	$I_{IN} = -12\text{mA}$	2.0		0.8	V
V_{IH}	High				-0.8	V
V_{IC}	Clamp				-1.2	V
Output voltage²						
V_{OL}	Low	$\overline{CE}_{1,2} = \text{Low}, \overline{CE}_{3,4} = \text{High}$ $I_{OUT} = 9.6\text{mA}$	2.4		0.45	V
V_{OH}	High					$I_{OUT} = -2.0\text{mA}$
Input current¹						
I_{IL}	Low	$V_{IN} = 0.45\text{V}$ $V_{IN} = 5.5\text{V}$			-100	μA
I_{IH}	High				40	μA
Output current¹						
I_{OZ}	Hi-Z state	$\overline{CE}_{1,2} = \text{High}, \overline{CE}_{3,4} = \text{Low}, V_{OUT} = 5.5\text{V}$ $\overline{CE}_{1,2} = \text{High}, \overline{CE}_{3,4} = \text{Low}, V_{OUT} = 0.5\text{V}$ $\overline{CE}_{1,2} = \text{Low}, \overline{CE}_{3,4} = \text{High}, V_{OUT} = 0\text{V}$ High stored	-15		40	μA
I_{OS}	Short circuit ⁴				-40	μA
					-70	mA
Supply current⁵						
I_{CC}		$V_{CC} = 5.25\text{V}$		125	175	mA
Capacitance						
C_{IN}	Input	$\overline{CE}_{1,2} = \text{High}, V_{CC} = 5.0\text{V}$ $V_{IN} = 2.0\text{V}$ $V_{OUT} = 2.0\text{V}$			5	pF
C_{OUT}	Output				8	pF

NOTES:

- Positive current is defined as into the terminal referenced.
- All voltages with respect to network ground.
- Typical values are at $V_{CC} = 5\text{V}$, $T_{amb} = +25^{\circ}\text{C}$.
- Duration of the short circuit should not exceed 1 second.
- Measured with all inputs grounded and all outputs open.

8K-bit TTL bipolar PROM (1024 × 8)

82S181 / 82S181A

AC ELECTRICAL CHARACTERISTICS

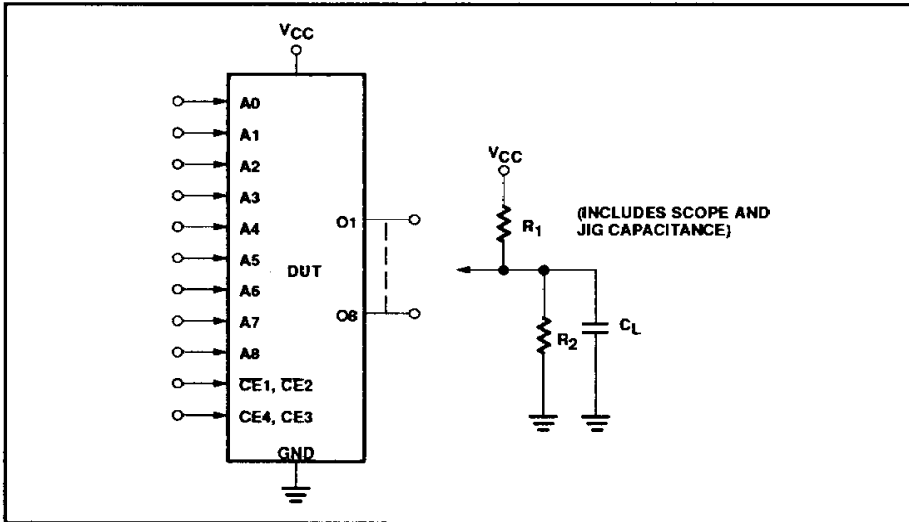
$R_1 = 470\Omega$, $R_2 = 1k\Omega$, $C_L = 30pF$, $0^\circ C \leq T_{amb} \leq +75^\circ C$, $4.75V \leq V_{CC} \leq 5.25V$

SYMBOL	PARAMETER	TO	FROM	N82S181			N82S181A			UNIT
				Min	Typ ¹	Max	Min	Typ ¹	Max	
Access time²										
t_{AA}		Output	Address		50	70		45	55	ns
t_{CE}		Output	Chip Enable		25	40		25	40	ns
Disable time³										
t_{CD}		Output	Chip Disable		25	40		25	40	ns

NOTES:

1. Typical values are $V_{CC} = 5V$, $T_{amb} = +25^\circ C$.
2. Tested at an address cycle time of $1\mu s$.
3. Measured at a delta of 0.5V from Logic Level with $R_1 = 750\Omega$, $R_2 = 750\Omega$ and $C_L = 5pF$.

TEST LOAD CIRCUIT



VOLTAGE WAVEFORM

